

Video Difference **Amplifier**

FEATURES

	Differential	or S	Single-Ended	Gain	Block	(Adjustable)
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■ -3dB Bandwidth, A _V = ±2	80MHz
■ Slew Rate	500V/μs

■ Low Cost

 Output Current ±50mA Settling Time 180ns to 0.1%

■ CMRR @ 10MHz >40dB Differential Gain Error 0.2%

 Differential Phase Error 0.08°

Single +5V Operation

Drives Cables Directly

Output Shutdown

APPLICATIONS

- Line Receivers
- Video Signal Processing
- Cable Drivers
- Oscillators
- Tape and Disc Drive Systems

DESCRIPTION

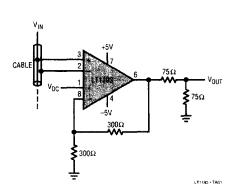
INVERTING INPUT

The LT1193 is a video difference amplifier optimized for operation on $\pm 5V$, and a single +5V supply. This versatile amplifier features uncommitted high input impedance (+) and (-) inputs, and can be used in differential or singleended configurations. Additionally, a second set of inputs give gain adjustment and DC control to the differential amplifier.

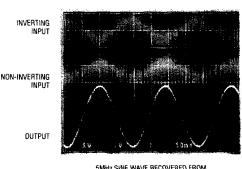
The LT1193's high slew rate, 500V/µs, wide bandwidth, 80MHz, and ±50mA output current, make it ideal for driving cables directly. The shutdown feature reduces the power dissipation to a mere 15mW, and allows multiple amplifiers to drive the same cable.

The LT1193 is available in 8-pin miniDIPs and SO packages.

Cable Sense Amplifier for Loop Through Connections with DC Adjust



Recovered Signal from Common Mode Noise

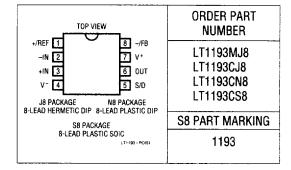


5MHz SINE WAVE RECOVERED FROM COMMON MODE NOISE, Au = +2 LT1193 - TAGZ

ABSOLUTE MAXIMUM RATINGS

PACKAGE/ORDER INFORMATION

Total Supply Voltage (V + to V -)18V
Differential Input Voltage± 6V
Input Voltage±V _S
Output Short Circuit Duration (Note 1) Continuous
Operating Junction Temperature Range
LT1193M55°C to 150°C
LT1193C0°C to 150°C
Max. Junction Temperature See Pkg. Descriptions
Storage Temperature Range65°C to 150°C
Lead Temperature (Soldering, 10 sec.)300°C



ELECTRICAL CHARACTERISTICS $v_8 = \pm 5 V$, $v_{REF} = 0 V$, $R_{FB1} = 900 \Omega$ from pins 6 to 8, $R_{FB2} = 100 \Omega$ from pin 8 to ground, $R_L = R_{FB1} + R_{FB2} = 1 k$ (Note 2), $T_A = 25^{\circ} C$, $C_L \leq 10 pF$, pin 5 open circuit, unless otherwise noted.

				LT1193M/C		
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Vos	Input Offset Voltage	Both Inputs, (Note 3)		2.0	12.0	mV
los	Input Offset Current	Either Input		0.2	3.0	μА
I _B	Input Bias Current	Either Input		±0.5	±3.5	μА
e _n	Input Noise Voltage	f ₀ = 10kHz		50		nV/√Hz
in	Input Noise Current	f ₀ = 10kHz		4.0		pA/√Hz
R _{IN}	Input Resistance	Either Input		100		kΩ
Cin	Input Capacitance	Either Input		2.0		pF
V _{IN LIM}	Input Voltage Limit	(Note 4)		1.3		V
	Input Voltage Range		-2.5		+3.5	٧
CMRR	Common Mode Rejection Ratio	V _{CM} = - 2.5V to +3.5V	60	75		dB
PSRR	Power Supply Rejection Ratio	V _S = ± 2.375V to ± 8V	60	75		dB
Vout	Output Voltage Swing	$V_S = \pm 5V, R_L = 1k$	±3.8	±4.0		V
1		$V_S = \pm 8V, R_L = 1k$	±6.8	±7.0		1
		$V_S = \pm 8V, R_L = 100\Omega$	6.4	6.6		1
GE	Gain Error	$V_0 = \pm 3V, R_L = 1k$		0.1	1.0	%
		$R_L = 100\Omega$		0.1	1.2	1
SR	Slew Rate	$V_0 = \pm 2V$, $R_L = 300\Omega$, (Note 5, 10)	350	500		V/µs
FPBW	Full Power Bandwidth	V ₀ = 6Vp-p, (Note 6)	18.5	26.5		MHz
BW	Small Signal Bandwidth			9.0		MHz
t _r , t _f	Rise Time, Fall Time	$A_V = +50$, $V_0 = \pm 1.5V$, 20% to 80% (Note 10)	110	160	210	ns
t _{PD}	Propagation Delay	R _L = 1k, V ₀ = ±125mV, 50% to 50%		15		ns
	Overshoot	V ₀ = ±50mV		0	·	%
t _s	Settling Time	3V Step. 0.1%, (Note 7)		180		ns
Diff A _V	Differential Gain	$R_L = 150\Omega$, $A_V = +2$, (Note 8)		0.2		%
Diff Ph	Differential Phase	$R_L = 150\Omega$, $A_V = +2$, (Note 8)		0.08		Deg. p-p
Is	Supply Current			35	43	mA
-	Shutdown Supply Current	Pin 5 at V		1.3	2.0	mA

ELECTRICAL CHARACTERISTICS $V_S=\pm5V,\ V_{REF}=0V,\ R_{FB1}=900\Omega$ from pins 6 to 8, $R_{FB2}=100\Omega$ from pin 8 to ground, $R_L=R_{FB1}+R_{FB2}=1k$ (Note 2), $T_A=25^{\circ}C,\ C_L\leq 10pF,\ pin 5$ open circuit, unless otherwise neted.

SYMBOL	PARAMETER	CONDITIONS	MIN	LT1193M, TYP	C MAX	UNITS
I _{S/D}	Shutdown Pin Current	Pin 5 at V		20	50	μА
t _{on}	Turn On Time	Pin 5 from V ⁻ to Ground, R _L = 1k		300		ns
t _{off}	Turn Off Time	Pin 5 from Ground to V ⁻ , R _L ≈ 1k		200		ns

ELECTRICAL CHARACTERISTICS $v_{S^+}=+5v, \ v_{S^-}=0v, \ v_{REF}=+2.5v, \ R_{FB1}=900\Omega$ from pins 6 to 8, $R_{FB2}=100\Omega$ from pin 8 to v_{REF} , $R_L=R_{FB1}+R_{FB2}=1k$ (Note 2), $v_{A}=25^{\circ}C, \ C_L\leq 10pF$, pin 5 open circuit, unless otherwise noted.

				T	LT1193M	/C	
SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Vos	Input Offset Voltage	Both Inputs, (Note 3)			3.0	15	mV
los	Input Offset Current	Either Input			0.2	3.0	μА
l _B	Input Bias Current	Either Input			±0.5	±3.5	μА
-	Input Voltage Range			+2.0		+3.5	V
CMRR	Common Mode Rejection Ratio	$V_{CM} = +2.0V \text{ to } +3.5V$		55	70		dB
V _{OUT}	Output Voltage Swing	$R_L = 100\Omega$ to Ground	V _{OUT} High	3.6	3.8		V
			V _{OUT} Low		0.25	0.4	
SR	Slew Rate	$V_0 = +1V \text{ to } +3V$			250		V/µs
BW	Small Signal Bandwidth				8.0		MHz
Is	Supply Current				32	40	mA
	Shutdown Supply Current	Pin 5 at V			1.3	2.0	mA
I _{S/D}	Shutdown Pin Current	Pin 5 at V -			20	50	μА

ELECTRICAL CHARACTERISTICS $v_S=\pm 5V, \ v_{REF}=0V, \ R_{FB1}=900\Omega$ from pins 6 to 8, $R_{FB2}=100\Omega$ from pin 8 to ground, $R_L=R_{FB2}=1k$ (Note 2), $T_A=-55^{\circ}C \le T_A \le 125^{\circ}C, \ C_L \le 10pF$, pin 5 open circuit, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	LT1193I TYP	MAX	UNITS
Vos	Input Offset Voltage		•		2.0	16	mV
$\Delta V_{OS}/\Delta T$	Input V _{OS} Drift		•		20		μV/°C
los	Input Offset Current		•		0.8	5.0	μА
IB	Input Bias Current		•		±1.0	±5.5	μА
	Input Voltage Range		•	-2.5		+3.5	V
CMRR	Common Mode Rejection Ratio	$V_{CM} = -2.5V \text{ to } +3.5V$	•	53	70		dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 2.375V \text{ to } \pm 5.0V$	•	53	70		dB
V _{OUT}	Output Voltage Swing	R _L = 1k	•	3.6	4.0		V
		$V_S = \pm 8V, R_L = 100\Omega$	•	6.0	6.5		
GE	Gain Error	$V_0 = \pm 3V, R_L = 1k$	•		0.2	1.2	%
Is	Supply Current		•		35	43	mA
	Shutdown Supply Current	Pin 5 at V -, (Note 9)	•		1.3	2.2	mA
I _{S/D}	Shutdown Pin Current	Pin 5 at V	•		20		μА

ELECTRICAL CHARACTERISTICS $V_S=\pm 5V,~V_{REF}=0V,~R_{FB1}=900\Omega$ from pins 6 to 8, $R_{FB2}=100\Omega$ from pin 8 to ground, $R_L=R_{FB1}+R_{FB2}=1k$ (Note 2), $T_A=0^{\circ}C \le T_A \le 70^{\circ}C,~C_L \le 10pF$, pin 5 open circuit, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	LT1193 TYP	C MAX	UNITS
Vos	Input Offset Voltage		•		2.0	14	mV
ΔV _{0S} /ΔΤ	Input V _{OS} Drift		•		20		μV/°C
los	Input Offset Current		•		0.2	3.5	μА
I _B	Input Bias Current		•		±0.5	±4.0	μА
	Input Voltage Range		•	-2.5		+3.5	٧
CMRR	Common Mode Rejection Ratio	$V_{CM} = -2.5V \text{ to } +3.5V$	•	55	70	•	dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 2.375V \text{ to } \pm 5.0V$	•	55	70		dB
V _{OUT}	Output Voltage Swing	R _L = 1k	•	3.7	4.0		· V
		$R_L = 100\Omega$	•	6.2	6.6]
GE	Gain Error	V ₀ = ±3V, R _L = 1k	•		0.2	1.2	%
Is	Supply Current		•		35	43	mA
	Shutdown Supply Current	Pin 5 at V -, (Note 9)	•		1.3	2.1	mA
I _{S/D}	Shutdown Pin Current	Pin 5 at V	•		20		μА

The ullet denotes the specifications which apply over the full operating temperature range.

Note 1: A heat sink is required to keep the junction temperature below absolute maximum when the output is shorted.

Note 2: When R_L = 1k is specified, the load resistor is R_{FB1} + R_{FB2} , but when R_L = 100 Ω is specified, then an additional 100 Ω is added to the output

Note 3: V_{0S} measured at the output (pin 6) is the contribution from both input pair, and is input referred.

Note 4: $V_{IN\ LIM}$ is the maximum voltage between $-V_{IN}$ and $+V_{IN}$ (pin 2 and pin 3) for which the output can respond.

Note 5: Slew rate is measured between $\pm 2V$ on the output, with a $\pm 1V$ input step, $A_V = +3$.

Note 6: Full power bandwidth is calculated from the slew rate measurement: FPBW = $SR/2\pi Vp$.

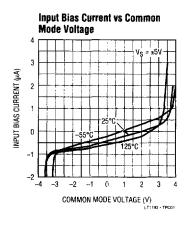
Note 7: Settling time measurement techniques are shown in "Take the Guesswork Out of Settling Time Measurements," EDN. September 19, 1985

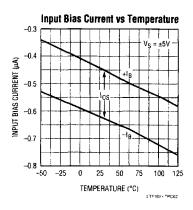
Nate 8: NTSC (3.58MHz).

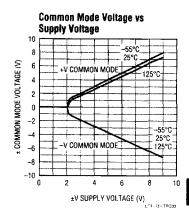
Note 9: See Applications section for shutdown at elevated temperatures. Do not operate the shutdown above T_{.1} > 125°C.

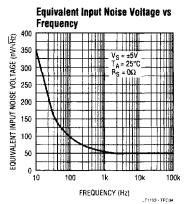
Note 10: AC parameters are 100% tested on the ceramic and plastic DIP packaged parts (J and N suffix) and are sample tested on every lot of the SO packaged parts (S suffix).

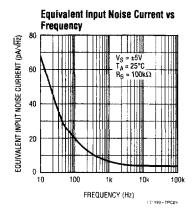
TYPICAL PERFORMANCE CHARACTERISTICS

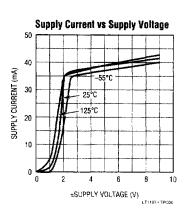


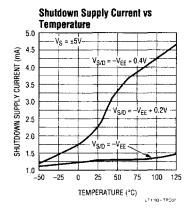


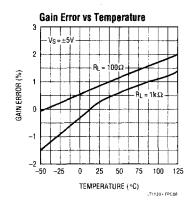


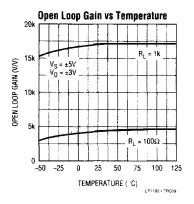




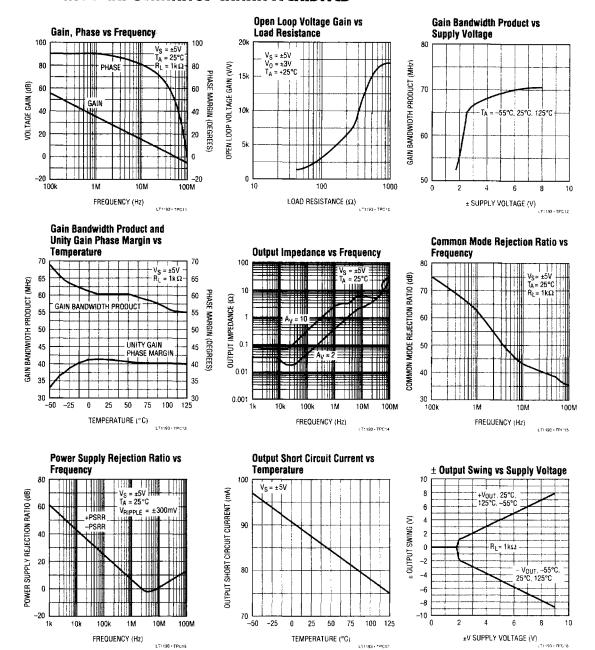




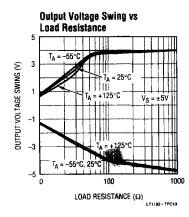


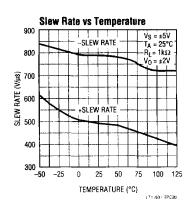


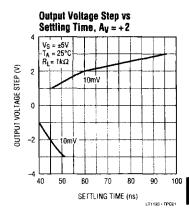
TYPICAL PERFORMANCE CHARACTERISTICS



TYPICAL PERFORMANCE CHARACTERISTICS





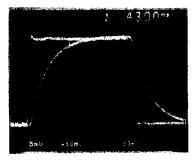


Large Signal Transient Response



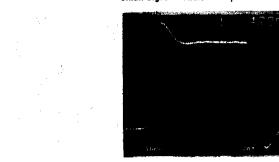
 $A_V = +2, \ R_L \approx 150 \Omega, \ R_{FB} = 300 \Omega, \ R_{\tilde{G}} \approx 300 \Omega$

Small Signal Transient Response



A_V = -10, SMALL SIGNAL RISE TIME = 43ns

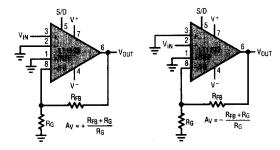
Small Signal Transient Response

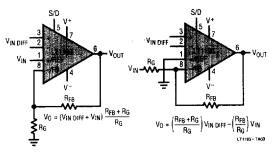


 $A_V = +2, \ R_{FB} = 300\Omega, \ R_G = 300\Omega, \ OVERSHOOT = 25\%, \\ RISE \ TIME = 4.7ns$



The LT1193 is a video difference amplifier which has two uncommitted high input impedance (+) and (-) inputs. The amplifier has one set of inputs which can be used for reference and feedback. Additionally, this set of inputs give gain adjust, and DC control to the differential amplifier. The voltage gain of the LT1193 is set like a conventional operational amplifier. Feedback is applied to pin 8, and it is optimized for gains of 2 or greater. The amplifier can be operated single-ended by connecting either the (+) or (-) inputs to the +/Reference pin 1. The voltage gain is set by the resistors: $(R_{FB} + R_{\rm G})/R_{\rm G}$.



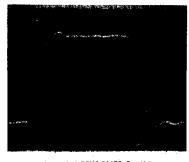


The primary usefulness of the LT1193 is in converting high speed differential signals to a single-ended output. The amplifier has common mode rejection beyond 50MHz, and a full power bandwidth of 40MHz at 4Vp-p. Like the single-ended case, the differential voltage gain is set by the external resistors: $(R_{FB} + R_G)/R_G$. The maximum input differential signal for which the output will respond is approximately $\pm 1.3V$.

Power Supply Bypassing

The LT1193 is quite tolerant of power supply bypassing. In some applications a $0.1\mu F$ ceramic disc capacitor placed 1/2 inch from the amplifier is all that is required. A scope photo of the amplifier output with no supply bypassing is used to demonstrate this bypassing tolerance, $R_L = 1k\Omega$.

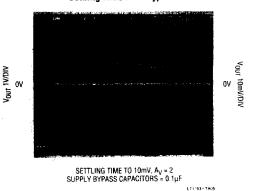
No Supply Bypass Capacitors



 $A_V = +10$, IN DEMO BOARD, $R_L = 1k\Omega$

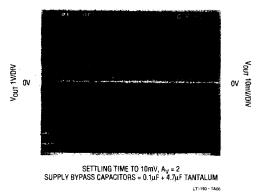
In many applications and those requiring good settling time it is important to use multiple bypass capacitors. A $0.1\mu F$ ceramic disc in parallel with a $4.7\mu F$ tantalum is recommended. Two oscilloscope photos with different bypass conditions are used to illustrate the settling time characteristics of the amplifier. Note that although the output waveform looks acceptable at 1V/div, when

Settling Time Poor Bypass





Settling Time Good Bypass

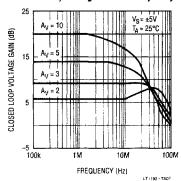


amplified to 10mV/div the settling time to 10mV is 347ns for the $0.1\mu F$ bypass; the time drops to 96ns with multiple bypass capacitors.

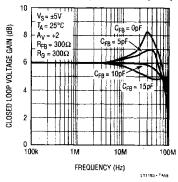
Operating With Low Closed Loop Gains

The LT1193 has been optimized for closed loop gains of 2 or greater; the frequency response illustrates the obtainable closed loop bandwidths. For a closed loop gain of 2 the response peaks about +2dB. Peaking can be minimized by keeping the feedback elements below $1k\Omega$, and can be eliminated by placing a capacitor across the feedback resistor, (feedback zero). This peaking shows up as time domain overshoot of about 40%. With the feedback capacitor it is eliminated.

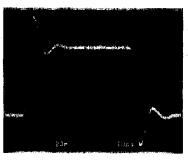
Closed Loop Voltage Gain vs Frequency



Closed Loop Voltage Gain vs Frequency



Small Signal Transient Response



 $A_V = +2$, OVERSHOOT = 40%, $R_{FB} = 1$ k, $R_G = 1$ k

Small Signal Transient Response



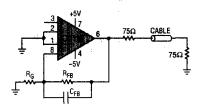
 A_V = +2, WITH 8pF FEEDBACK CAPACITOR RISE TIME = 3.75ns, R_{FB} = 1k, R_G = 1k

Cable Terminations

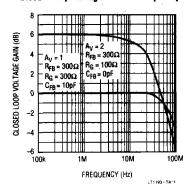
The LT1193 video difference amplifier has been optimized as a low cost cable driver. The ±50mA guaranteed output current enables the LT1193 to easily deliver 7.5Vp-p into 100Ω , while operating on $\pm 5V$ supplies, and gains >3. On a single 5V supply the LT1193 can swing 2.6Vp-p for gains ≥2.

When driving a cable it is important to terminate the cable to avoid unwanted reflections. This can be done in one of two ways: single termination or double termination. With single termination, the cable must be terminated at the receiving end (75 Ω to ground) to absorb unwanted energy. The best performance can be obtained by double termination (75 Ω in series with the output of the amplifier, and 75Ω to ground at the other end of the cable). This termination is preferred because reflected energy is absorbed at each end of the cable. When using the double termination technique it is important to note that the signal is attenuated by a factor of 2, or 6dB. The cable driver has a -3dB bandwidth of 80MHz while driving a 150 Ω load.

Double Terminated Cable Driver



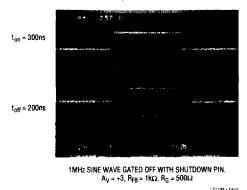
Closed Loop Voltage Gain vs Frequency



Using the Shutdown Feature

The LT1193 has a unique feature that allows the amplifier to be shutdown for conserving power, or for multiplexing several amplifiers onto a common cable. The amplifier will shutdown by taking pin 5 to V⁻. In shutdown, the amplifier dissipates 15mW while maintaining a true high impedance output state of $15k\Omega$ in parallel with the feedback resistors. The amplifiers may be connected inverting. non-inverting or differential for MUX applications. When the output is loaded with as little as $1k\Omega$ from the amplifier's feedback resistors, the amplifier shuts off in 200ns. This shutoff can be under the control of HC CMOS operating between OV and -5V.

Output Shutdown



The ability to maintain shutoff is shown on the curve Shutdown Supply Current vs Temperature in the Typical Performance Characteristics section. At very high elevated temperatures it is important to hold the shutdown pin close to the negative supply to keep the supply current

from increasing.

Murphy Circuits

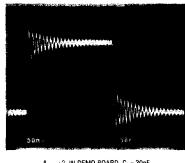
There are several precautions the user should take when using the LT1193 in order to realize its full capability. Although the LT1193 can drive a 30pF in gains as low as 2, isolating the capacitance with 10Ω can be helpful. Precautions primarily have to do with driving large capacitive loads.

Other precautions include:

1. Use a ground plane (see Design Note 50, High Frequency Amplifier Evaluation Board).

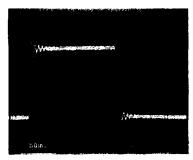
- 2. Do not use high source impedances. The input capacitance
- of 2pF, and R_S = 10k Ω for instance, will give an 8MHz –3dB bandwidth.
- 3. PC board socket may reduce stability.
- 4. A feedback resistor of $1k\Omega$ or lower reduces the effects of stray capacitance at the inverting input. (For instance, closed loop gain of ± 2 can use $R_{FB} = 300\Omega$ and $R_{G} = 300\Omega$.)

Driving Capacitive Load



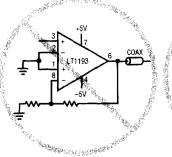
 A_V = +2, IN DEMO BOARO, C_L = 30pF R_{FB} = 1k, R_G = 1k

Driving Capacitive Load

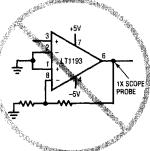


A_V = +2, IN DEMO 80ARD, C_L = 30pF WITH 10Ω ISOLATING RESISTOR

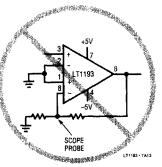
Murphy Circuits



An Unterminated Cable Is a Large Capacitive Load



A 1X Scope Probe is a Large Capacitive Load



A Scope Probe on the Inverting input Reduces Phase Margin

SIMPLIFIED SCHEMATIC

